## **Theory of the Fabry-Pérot quantum Hall interferometer**

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We analyze interference phenomena in the quantum-Hall analog of the Fabry-Pérot interferometer, exploring the roles of the Aharonov-Bohm effect, Coulomb interactions, and fractional statistics on the oscillations of the resistance as one varies the magnetic field *B* and/or the voltage  $V_G$  applied to a side gate. Coulomb interactions couple the interfering edge mode to localized quasiparticle states in the bulk, whose occupation is quantized in integer values. For the integer quantum Hall effect, if the bulk-edge coupling is absent, the resistance exhibits an Aharonov-Bohm (AB) periodicity, where the phase is equal to the number of quanta of magnetic flux enclosed by a specified interferometer area. When bulk-edge coupling is present, the actual area of the interferometer oscillates as a function of *B* and  $V_G$ , with a combination of smooth variation and abrupt jumps due to changes in the number of quasiparticles in the bulk of the interferometer. This modulates the AB phase and gives rise to additional periodicities in the resistance. In the limit of strong interactions, the amplitude of the AB oscillations becomes negligible, and one sees only the new "Coulomb-dominated" (CD) periodicity. In the limits where either the AB or the CD periodicities dominate, a color map of resistance will show a series of parallel stripes in the *B*-*VG* plane, but the two cases show different stripe spacings and slopes of opposite signs. At intermediate coupling, one sees a superposition of the two patterns. We discuss dependences of the interference intensities on parameters including the temperature and the backscattering strengths of the individual constrictions. We also discuss how results are modified in a fractional quantized Hall system, and the extent to which the interferometer may demonstrate the fractional statistics of the quasiparticles.

DOI: [10.1103/PhysRevB.83.155440](http://dx.doi.org/10.1103/PhysRevB.83.155440) PACS number(s): 73*.*43*.*Cd, 73*.*43*.*Jn, 85*.*35*.*Ds, 73*.*23*.*Hk

## **I. INTRODUCTION**

## **A. Background**

In the past few years there has been a surge of interest in electronic interference phenomena in the regime of the quantum Hall effect. This interest, both theoretical $1-7$  and experimental, $8-23$  results in large part from the hope of utilizing interference to probe unconventional statistics in various fractional quantum Hall states. Interestingly, interferometer experiments have led to puzzling results even in the integer regime, which have posed a challenge to our theoretical understanding.

Arguably the simplest realization of a quantum Hall interferometer is an analog to the optical Fabry-Pérot device. It is constructed of a Hall bar perturbed by two constrictions, each of which introduces an amplitude for interedge scattering. (See Fig. [1.](#page-1-0)) The backscattering probability of a wave packet that goes through the constrictions is then determined by an interference of trajectories. In the limit of weak interedge scattering, two trajectories interfere, corresponding to scattering across each of the two constrictions. As the scattering amplitudes get larger, multiple reflections play a more significant role.

In our analysis, we assume that the two constrictions forming the interferometer are identical to each other, and that there is a single partially transmitted edge channel penetrating the two constrictions. This partially transmitted channel separates two quantized Hall states corresponding to rational filling factors  $v_{\text{in}} > v_{\text{out}}$ , with  $v_{\text{out}}$  being closer to the sample edge. In addition to the interfering channel, there may be a number of outer edge channels that are fully transmitted through the two constrictions, whose number we denote by  $f_T \geq 0$ . The situations considered in this paper assume that

the states *ν*in and *ν*out are either integer states or integers plus a fraction described in the composite fermion picture, where the partially filled Landau level (LL) is less than half full. In particular, this means that all edge states propagate in the same direction. We also assume that the mean free path for scattering of particles between parallel-propagating edge states is larger than the perimeter of the interferometer. $24,25$  We shall refer to the cases where *ν*in is integer or fractional as an integer quantum Hall effect (IQHE) or fractional quantum Hall effect (FQHE) interferometer, respectively.

For noninteracting electrons, there will be an interference between electrons backscattered at the two constrictions, with a relative phase determined by the Aharonov-Bohm (AB) effect. It is periodic in the magnetic flux  $\Phi$  enclosed by the loop defined by the two interfering trajectories, with a period of one flux quantum  $\Phi_0$  (we define the flux quantum as  $\Phi_0 = h/|e| > 0$ , where  $e < 0$  is the electron charge.). For a uniform magnetic field *B* the flux is  $\Phi = BA_I$ , with  $A_I$ being the area of the interference loop. Experimentally, it is customary to affect this flux through two experimental knobs: the magnetic field *B*, and the voltage  $V_G$  on a gate that affects the area of the loop. The gate may be positioned above the interference loop or to its side. For fractional quantum Hall states, where electron-electron interaction is essential, the relative phase is made of two contributions, an AB phase that is scaled down by the charge of the interfering quasiparticle, and an anyonic phase, accumulated when one quasiparticle encircles another.

Experimentally, several remarkable observations were  $made^{10,12,13,16,19}$  when interference was measured in small Fabry-Pérot interferometers, e.g., with an interference loop

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FIG. 1. Fabry-Pérot interferometer in the IQHE regime, with one totally transmitted edge mode  $f_T = 1$ . The partially transmitted edge mode separates quantized Hall regions with nominal filling  $v_{\text{out}} = 1$ and  $v_{\text{in}} = 2$ . A third edge mode is totally reflected before entering the constrictions, because the electron density in the constriction is smaller than in the center of the interferometer. Dotted lines in each constriction show the locations of scattering between the two edges, indicated here as weak backscattering.

whose area is <sup>∼</sup><sup>5</sup> *<sup>μ</sup>*m2. One observation was that when the magnetic field is varied, the backscattering current oscillates as a function of the magnetic field, but the period  $\Delta B$  of the oscillations was not  $\Phi_0/A_I$ . Rather, it was given by  $\Phi_0/f_T A_I$ , which means, in particular, that there was no dependence on *B* for  $f_T = 0$ . The period  $\Delta B$  did not change when  $v_c$ , the filling factor at the center of the constriction was varied in the range between  $f_T$  and  $f_T + 1$ , and the backscattering probability for the partially transmitted edge state varied from strong to weak. Second, when the lines of constant phase in the *B*-*VG* plane were examined, $13,16$  they were found to have a positive slope, which is the opposite sign relative to what one would naively expect for an AB interference effect (Similar lines were observed also in Ref. [23,](#page-15-0) where a scanning probe was used to probe the spectrum of excitations of a spontaneously formed quantum dot.) By contrast, in interferometers that were sufficiently large (e.g., area  $\sim$ 17  $\mu$ m<sup>2</sup>), where the center island was covered by a screening top gate, the conventional AB pattern was observed, with field period  $\Phi_0/A_I$  and a negative slope for the lines of constant phase. A similar AB behavior was also observed in some small interferometers.<sup>17,18</sup>

Previous works have explained that the periodicities and slopes in the Fabry-Pérot interferometer are affected by the Coulomb interactions and the discreteness of electronic charges.<sup>[6,13,16](#page-15-0)</sup> The regime of parameters where lines of constant phase have a positive slope (or zero slope in the case  $f_T = 0$ ) will be referred to as the Coulomb-dominated (CD) regime, in contrast with the AB regime.

In this paper, we present a general picture of the interplay of the AB and CD regimes in the Fabry-Pérot interferometer, and elucidate the way this interplay is determined by the combination of Coulomb interaction and charge discreteness. We limit our analysis of the FQHE to Abelian states. We hope to extend our present study to the case of non-Abelian states in a future publication.

#### **B. Summary of our results**

Before we turn into a detailed discussion, we summarize our results and present a physical way of understanding them.

Generally, when electron-electron interactions are taken into account, we find that the area  $A_I$  enclosed by the interfering edge state is not a smooth monotonic function of the magnetic field and gate voltage. Rather, we find that  $A_I$  has the form

$$
A_I = \bar{A}(B, V_G) + \delta A_I,\tag{1}
$$

where  $A$  is a slowly varying function of its arguments, while *δAI* has rapid oscillations, with a period in *B* on the scale of one flux quantum or a change in  $V_G$  that adds one electron. We assume throughout that the area  $A_I$  is large enough to enclose many electrons and flux quanta, so that the oscillation periods occur on a scale where there is only a small fractional change in *B* or  $\overline{A}$ . The magnitude of  $\delta A_I$  will be smaller than  $\overline{A}$  by a similar factor of the inverse of the number of flux quanta in the system. Nevertheless, the oscillatory dependence of *δAI* on the magnetic field and  $V_G$  can have striking consequences on the interference pattern, as we shall see below. (To simplify our discussions, we shall also assume, except where otherwise stated, that the secular area *A* is only weakly dependent on the magnetic field *B*, i.e., that  $B\partial \overline{A}/\partial B$  is negligible compared to *A*.)

Typically, experiments measure the "diagonal resistance"  $R_D$ <sup>[22](#page-15-0)</sup> which is essentially the two-terminal Hall resistance of the interferometer region. We find that  $R<sub>D</sub>$  has an oscillatory part  $\delta R$ , which is a periodic function of *B* and  $\delta V_G$ . In the limit of weak backscattering it may be written as

$$
\delta R = \text{Re}\left(\sum_{m=-\infty}^{\infty} R_m e^{2\pi i (m\phi + \alpha_m \delta V_G)}\right),\tag{2}
$$

where

$$
\phi \equiv B\bar{A}/\Phi_0,\tag{3}
$$

and the coefficients  $R_m, \alpha_m$  are real and only slowly varying functions of  $B$ ,  $V_G$ . The voltage  $V_G$  affects the phases  $e^{2\pi i(m\phi + \alpha_m \delta V_G)}$  in (2) in two ways. First, it affects the flux  $\phi$  through its effect on the area  $\overline{A}$ . Second, it affects the density in the bulk of the interferometer, indirectly affecting the interference through interactions of the edge with the bulk. The coefficients  $\alpha_m$  quantify the latter effect, which we will analyze further below.

For noninteracting electrons (the extreme AB limit), the weak backscattering limit has only one nonzero component in Eq. (2). That component is  $m = 1$ , with  $\alpha_1 = 0$ . Since the area  $\overline{A}$  should be a monotonically increasing function of  $V_G$ , we find that for small changes in  $B$  and  $V_G$  the contours of constant phase are straight lines of negative slope in the *B*-*VG* plane. (When backscattering becomes stronger, multiple reflections lead to more harmonics of *m* showing up, but still  $\alpha_m = 0$ , so the slope does not change.) When plotted as a color-scale map in a  $B-V_G$  plane, the resistance  $R_D$  forms a set of parallel lines, such as the dominant features seen in Fig.  $2(a)$ .

Electron-electron interactions lead to two important differences between the quantum Hall interferometer and a naive AB interference experiment. First, as mentioned above, the area *AI* of the interference loop is not rigidly constrained *a priori*, but can fluctuate slightly. Thus, the area of the interference loop varies with magnetic field and the flux within the loop is generally not a simple linear function of the magnetic field. The position of the edge is related to the charge it encloses, and

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FIG. 2. (Color)  $\langle \delta R \rangle = \text{Re}(R_1 e^{2\pi i \phi} + R_{-fT} e^{-2\pi i f_T \phi})$  as a color map in the plane of *B* and  $V_G$ , for  $f_T = 2$ , with the parameter  $\gamma$  chosen equal to 3.5*β*. (a), (b), (c), (d), and (e) have, respectively,  $|R_{-2}/R_1| = 0, 0.5, 1, 2$ , and  $\infty$ , corresponding to the AB, mixed, and CD regimes. All Fourier components other than  $m = 1$  and  $m = -f_T$  are neglected. Alternating red and blue regions represent positive and negative values, respectively, while white signifies a value close to zero.

its variation in our model is a consequence of considerations of energy. Second, we model the region enclosed by the interference loop as one in which there are localized states close to the chemical potential. The number *NL* of electrons (in the IQHE regime) or quasiparticles (in the FQHE regime) that are localized in the bulk is an integer, and varies discretely. Due to considerations of energy, an abrupt change of occupation of a localized state as the magnetic field is varied affects also the position of the interfering edge, and hence induces an abrupt change in the flux enclosed by the interference loop.

Thus, as  $B$  or  $V_G$  vary, the phase accumulated by the interfering particle, *θ*, evolves in two ways: continuous evolution for as long as *NL* does not vary, and abrupt jumps for magnetic fields at which  $N_L$  abruptly changes. The continuous change results from the variation of the magnetic flux in the interference loop, both directly as a consequence of the varying *B*, and indirectly as a consequence of the variation of the loop's area  $A<sub>I</sub>$ . The abrupt change results from the effect of a variation of  $N_L$  on the area of the interference loop, and, in the FQHE, from the anyonic phase accumulated when fractionally charged quasiparticles encircle one another. Specifically, in the integer case,  $\theta$  is simply related to the field *B* and the area  $A_I$ by

$$
\theta = 2\pi B A_I / \Phi_0,\tag{4}
$$

while, for the FQHE states that we consider, we find

$$
\theta = 2\pi e_{\text{in}}^* \frac{BA_I}{\Phi_0} + N_L \theta_a,\tag{5}
$$

where  $\theta_a$  is the phase accumulated when one elementary quasiparticle of charge of the inner FQHE state *ν*in encircles another, and  $e_{\text{in}}^*$  is the charge of the quasiparticle. Here, and in the following, charge is to be measured in units of the (negative) electron charge *e*.

Within our model, both the rate of continuous evolution of the phase,  $d\theta/d\phi$ , and the size  $2\pi\Delta$  of the phase jump associated with a change of *NL* by −1, vary only slowly with *B* and *VG*. The same holds for the magnetic-field spacings between consecutive changes in *NL*.

In the extreme CD regime, for integer and fractional states alike, we find that a change of  $N_L$  is accompanied by a change of the area of the interference loop in such a way that the phase jump  $\Delta\theta$  is an unobservable integer multiple of  $2\pi$ . Coulomb interaction makes the area vary in such a way that

the continuous variation of the phase follows  $\frac{d\theta}{d\phi} = -2\pi \frac{v_{\text{out}}}{e_{\text{out}}^*}$ where  $e_{\text{out}}^*$  is the elementary charge of the outer  $v_{\text{out}}$  quantized Hall state. Neglecting the unobservable phase jumps, then,  $\theta = -2\pi \frac{v_{\text{out}}}{e_{\text{out}}^*}\phi$  for both the IQHE and the FQHE. This limit  $\overline{c}_{\text{out}}$  characterizes interferometers where the capacitive coupling of the bulk and the edge is strong. By contrast, in the extreme AB case, where the bulk and the interfering edge are not coupled, the area of the interference loop does not vary with *B* at all. Moreover,  $A_I$  does not vary when  $N_L$  varies. Thus, for integer states,  $\theta = 2\pi \phi$ . The fractional case is more complicated due to the anyonic phase  $\theta_a$ .

In between these two extremes,  $\theta$  is not proportional to  $\phi$ , and thus the Fourier transform of  $e^{i\theta}$  with respect to  $\phi$  has more than one component. For fractional states this is the case even in the extreme AB limit, due to the anyonic phase  $\theta_a$ . We find that for all the cases we consider, the components that appear in Eq. [\(2\)](#page-1-0) satisfy

$$
m = -\frac{v_{\text{out}}}{e_{\text{out}}^*} + g \frac{v_{\text{in}}}{e_{\text{in}}^*},
$$
 (6)

where *g* is an integer. Note that the ratios  $v_{\text{out}}/e_{\text{out}}^*$  and  $v_{\text{in}}/e_{\text{in}}^*$ are always integers, so the allowed values of *m* are integers as well. Moreover, due to the interaction,  $\alpha_m$  is not proportional to *m*, leading to different slopes of the equal phase lines for the different *m* components.

The CD limit and the AB limit are both defined in terms of the dominant values of  $g$  in  $(6)$ . In the extreme CD limit the only term that appears in the sum  $(2)$  is that of  $g = 0$  in  $(6)$ , both for integer and fractional states. In the extreme AB limit of integer states the only term that appears in [\(2\)](#page-1-0) is the naive AB term  $m = 1$  [or  $g = 1$  in (6)]. For fractional states, however, there will be coupling due to the phase jumps associated with the anyonic statistics of the quasiparticles, and one would not find pure AB behavior (only  $g = 1$ ), even when the Coulomb coupling between *NL* and *AI* can be neglected. Moreover, for FQHE states with  $v_{\text{in}} > 1$ , one finds that there is no value of *g* that generates  $m = 1$  in Eq. (6), so the naive AB period is completely absent in the weak backscattering limit.

In between the extreme AB and CD limits, all integers *g* appear in the Fourier decomposition of *δR*, with the relative dominance of the AB and CD components being determined by the value of  $\Delta$ . We find, under plausible assumptions, that  $0 <$  $\Delta$  < 1, and that if  $0 \le \Delta$  < 1/2 the AB term will dominate, whereas the CD term will dominate if  $1/2 < \Delta \leq 1$ .

<span id="page-3-0"></span>When the sum  $(2)$  is dominated by one term, as is the case in the CD limit and the AB limit of the IQHE, the color-scale plot of  $\delta R$  on the *B*-*V<sub>G</sub>* plane is characterized by a set of parallel lines, as is the case in Figs.  $2(a)$  and  $2(e)$ .

Figures  $2(b)-2(d)$  show the intermediate case, in which several values of *m* contribute, and  $\alpha_m$  is not proportional to *m*. Then the structure of  $R_D$  in the  $B-V_G$  plane assumes a form of a two-dimensional lattice, rather than a set of lines, as it would if  $\alpha_m$  stayed proportional to *m*. The periodic structure may be characterized by a unit cell in the  $B-V_G$  plane, described by two elementary lattice vectors **b** and **v**. In the most general case these vectors can have two arbitrary orientations in the plane. However, if the secular area  $\overline{A}$  is only weakly dependent on the magnetic field *B*, that is, if  $B\partial \bar{A}/\partial B \ll \bar{A}$ , we find that one of the elementary lattice vectors will be parallel to the *B* axis. Specifically, if  $V_G$  is held constant,  $\delta R$  will be unchanged when *B* is changed by the amount that increases  $\phi$ by one. (We emphasize that this is true even if the interfering particles are fractionally charged.) In our later discussions, rather than employing the direct lattice vectors **b** and **v**, we shall use a description in terms of their reciprocal lattice vectors.

The restriction of the Fourier harmonics to the values [\(6\)](#page-2-0) is valid only in the limit of weak backscattering. As the constrictions are further closed and the amplitude for backscattering becomes appreciable, all values of *m* appear in [\(2\)](#page-1-0). In the limit where this amplitude is strong, oscillations in the reflection probability turn into transmission resonances. The spacing between these resonances varies with the degree of coupling between the bulk and the edge. Generally, a transmission resonance occurs when the almost closed interfering edge has a degeneracy point, at which it may accommodate an extra electron (for the IQHE) or quasiparticle (for the FQHE) at no extra energy cost. In the AB limit, it is the energy of the edge, decoupled from the localized charges it encloses, that should be invariant to adding an extra charge carrier. At the integer quantum Hall regime, that would give rise to one transmission resonance per every flux quantum. In the CD limit, when the introduction of localized charges affects the energy of the edge through their mutual coupling, there would be *ν*<sub>out</sub>/*e*<sup>\*</sup><sub>out</sub> resonances per quantum of flux, in both the IQHE and the FQHE. Thus, the distinction between the AB and CD limits holds even in the limit of a closed interferometer, where the interfering edge almost becomes a quantum dot.

As should be clear from the discussion above, the form of *δR* depends crucially on the continuous and abrupt phase variations  $d\theta/d\phi$  and  $\Delta\theta$ . Both of these quantities depend on energy considerations, since the interferometer's area is a property of thermal equilibrium. We model the energy of the interferometer in terms of a capacitor network. The parameters of the model, describing the self-capacitance of the interfering edge, the self-capacitance of the localized quasiparticles, the mutual capacitance of the two, and the capacitive coupling of the gate to the interferometer, depend on microscopic parameters which we cannot accurately calculate at this point. However, we are able to give some insights into the way in which various parameters should vary with details of the systems, including particularly the perimeter and area of the interference loop.

## **C. The structure of the paper**

The structure of the paper is as follows. In Sec. II we deal with the weak backscattering limit. We identify what we believe to be the important degrees of freedom in the interferometer, express the phase  $\theta$  in terms of these degrees of freedom, and introduce an energy functional in terms of these degrees of freedom. In Sec. [III](#page-7-0) we calculate the thermal average of  $e^{i\theta}$ , which is the factor that determines the interference contribution to  $R<sub>D</sub>$  in the weak backscattering limit, and distinguish between the AB and CD limits. In Sec. [IV](#page-9-0) we extend the discussion to the regime of intermediate backscattering, and in Sec. [V](#page-10-0) to the regime of strong backscattering. In Sec. [VI](#page-11-0) we exemplify the way in which the energy parameters for the interfering edge and the localized states can be influenced by coupling to edge states that are fully transmitted, by solving in detail two simple models. In Sec. [VII](#page-12-0) we compare our findings to earlier experimental and theoretical works. Finally, we summarize our results in Sec. [VIII.](#page-13-0)

For the convenience of the reader, we include a table with a list of the main symbols used in the paper, their brief description, and a pointer to the section in which they are defined.

## **II. THE PHYSICAL MODEL—WEAK BACKSCATTERING CASE**

In this section we introduce the physical model on which we base our analysis of the weak backscattering limit. We start with the IQHE interferometers, and then generalize to the FQHE ones.

In the weak backscattering limit there should be an oscillatory part of the backscattered resistance given by

$$
\delta R \propto \text{Re}[r_1 r_2^* \langle e^{i\theta} \rangle],\tag{7}
$$

where  $r_1, r_2$  are the reflection amplitudes at the two constrictions, and the angular brackets represent an average over thermal fluctuations. We focus here on measurements in the limit of small source-drain bias, so we may consider all leads to be at the same electrochemical potential *μ*. We assume the change in  $B$  and  $V_G$  to be small enough that we may neglect any changes in  $r_1$  and  $r_2$ , and associate oscillations in the resistance with oscillations in the phase factor  $\langle e^{i\theta} \rangle$ . Our analysis of the phase factor  $e^{i\theta}$  is based on the following picture of the edge of a quantum Hall fluid in the integer regime.

#### **A. Model for integer quantum Hall edges**

We expect that any  $LL$  *j* which is more than half filled in the bulk of the system will have a single chiral edge state that circulates along the edge of the system. $26$  For our discussion of the spatial location of this edge state, we assume that the electron density varies smoothly near the edge of the sample, on the scale of the magnetic length. We denote the local charge density by  $n(\vec{r})$  and define a local filling factor  $\bar{v}(\vec{r}) = n(\vec{r})\Phi_0/B$ . As disorder localizes states away from the center of a LL, the spatial location of the circulating edge state will be close to the point where the LL is half full, and the extended state crosses the Fermi level. For example, the location of the interfering edge state should be given, approximately, by the condition  $\bar{v}(\vec{r}) = f_T + 1/2$ . Note

Symbol	Short description	Section
$v_{\text{in}}\left(v_{\text{out}}\right)$	Filling factor inside (outside) the interfering edge state	I A
$f_T$	Number of fully transmitted edge states	I A
$\boldsymbol{B}$	Magnetic field	I A
$\triangle B$	Magnetic field periodicity	I A
$V_G$	Voltage applied to a gate	I A
$A_I$	Area of the interference loop	I A
Ā	Slowly varying part of $A_I$	I B
$\delta A_I$	Rapidly oscillating part of $A_I$	IB
$\mathcal{R}_D$	Diagonal resistance	I B
$\delta R$	Oscillatory part of $R_D$	I B
φ	Magnetic flux within the area $\bar{A}$	I B
$\alpha_m$	Quantifies the effect of $V_G$ on the bulk of the interferometer loop	I B
$N_L$	Number of electrons or quasiparticles localized in the bulk of the interferometer	I B
$\theta$	The interference phase	I B
$e_{\text{in}}^*$ $(e_{\text{out}}^*)$	The charge of a quasiparticle in the $v_{\text{in}}$ ( $v_{\text{out}}$ ) state	IB
$2\pi\Delta$	Jump in phase $\theta$ when $N_L$ varies by $-1$	I B
$\theta_a$	Anyonic phase	I B
$r_1,r_2$	Reflection amplitudes at constrictions 1,2	$\mathbf{I}$
$N_j^e, N_j^h$	Integer number of localized electrons and holes in the jth Landau level	II A
$K_I, K_{IL}, K_L$	Coupling constants in the energy functional describing the interferometer	II B
$\bar{q}$	Effective bulk background charge	II B
$\beta$	Quantifies the effect of $V_G$ on the area of the interferometer	II B
$\gamma$	Quantifies the effect of $V_G$ on the bulk background charge	II B
$\Delta \nu$	$v_{\text{in}} - v_{\text{out}}$	II C
$C_I, C_L, C_{IL}$	Reparametrization of $K_I, K_L, K_{IL}$ by effective capacitances	II D
$\mu_I, \mu_L$	Electrochemical potentials of the $I$ and $L$ regions	II D
w, L	Width and length of the region of nonuniform density near the loop's edge	$\rm II$ D
	Partition function	III B
$\stackrel{Z}{G}_{gh}$	Reciprocal lattice vectors of the 2D description of $\delta R(B, V_G)$	$IIIE$
λ	Describes the variation of $\overline{A}$ with $B$	$\rm III$ E
$\eta$	Describes the variation of $\bar{q}$ with B	$\rm III$ E
$P_R$	Reflection probability for the interfering edge state	IV
$\eta_{\pm}$	Interferometer scattering phase shifts	IV
$\rho(\epsilon)$	Density of states	IV
$\Delta \phi$	Flux spacing between resonances	V
$N_o$	Total number of electrons in the highest Landau level enclosed by the interfering edge channels	V

TABLE I. List of symbols, their brief description, and the section where they are defined.

that at least within the Hartree-Fock approximation, localized states will form in a partially full LL, even in the absence of external disorder, due to spontaneous breaking of translational symmetry, $27$  which may be loosely described as the formation of a Wigner crystal of electrons or holes.

The location of an edge state will separate two regions where the nominal filling factors *ν* differ by one; for the interfering edge state this change would be from  $v_{\text{out}}$  to  $v_{\text{in}}$ . (For the case of an IQHE interferometer, we assume that there are no intervening regions of FQHE in the constrictions or at the edges of the interferometer region.) However, in typical situations, we will not find that electronic states in the LL are entirely empty at positions outside the edge state or entirely full inside the edge state. This means that there will be a difference between the the local charge density  $n(\vec{r})$  and the ideal "condensate" charge density *νB*/ $\Phi$ <sub>0</sub>. The corresponding difference between the actual filling  $\overline{v}(\vec{r})$  and the nominal filling *ν* represents the contribution of "localized charges," which occur when the LL has a certain number of electrons

 $N_f^e$  in localized states outside the edge state, and a certain number  $N_f^h$  of unoccupied localized states (holes) inside the area delimited by the edge state. The quantities  $N_j^h$  and  $N_j^e$  are constrained to be integers, as they represent the occupations of localized states.

Although the localized electrons and holes are localized in a one-body approximation, they are not completely immobile. At any finite temperature, they will have a nonzero conductivity due to processes such as multiparticle hopping, and we assume that they can readjust their relative positions continuously on the experimental time scale for changes in the magnetic field or gate voltage.

In Ref. [28,](#page-15-0) Chklovskii, Shklovskii, and Glazman analyzed the region near the boundary of a Hall bar using a selfconsistent *Hartree* approximation, neglecting the influence of disorder. They found that in the quantized Hall regime the density profile can be described by a sequence of compressible and incompressible stripes: There are broad compressible stripes where a given LL is gradually filled up, and narrow <span id="page-5-0"></span>incompressible stripes, where, due to the excitation gap between consecutive LLs, the filling factor is exactly equal to an integer. We can make contact with that analysis by associating the broad compressible regions of Ref. [28](#page-15-0) with both the chiral edge states, in our description, and the regions containing electrons and holes that are localized but are still weakly mobile. Further, we can associate the narrow incompressible stripes of Ref. [28](#page-15-0) with the boundary between a region with localized holes, i.e., a region with density  $n(\vec{r}) < vB/\Phi_0$ , and a neighboring region with localized electrons, i.e., with  $n(\vec{r}) > vB/\Phi_0.$ 

We assume that any incompressible regions, which might occur where the local filling  $\bar{\nu}$  is very close to an integer, are sufficiently narrow that such regions have at most a minor affect on the overall charge distribution of the system, and that they are narrow enough so that electrons can easily cross between the inner and outer edges of the region, by either tunneling or thermal activation, on a laboratory time scale. Of course, on a very short time scale, such as the transit time for an electron to move around the interferometer, it should not only be impossible for an electron to cross an incompressible strip, but for an electron to move across a region of localized states; so the effective quantized Hall region, where the local  $\sigma_{xx}$  is small and  $\sigma_{xy}$  is close to a quantized value  $ve^2/h$ , will be much wider than the incompressible strip itself. However, on a laboratory time scale, the interior of the island should behave as a set of metallic regions: The localized charges will arrange themselves to give a constant electrochemical potential in equilibrium, within each class of localized states.<sup>29</sup> As a result of the integer constraints on the total occupation numbers  $N_f^e$  and  $N_f^h$ , however, there can be small differences between the electrochemical potentials of various classes of localized states and that of the adjacent edge states or leads. Experimental support for this picture was found in Ref. [23.](#page-15-0)

In our analysis below, we shall neglect any changes in the number of electrons or holes localized in regions outside the interfering edge state, and keep track only of changes in the total number that are localized in the bulk of the interferometer, inside the area enclosed by the interfering edge state, which we denote by  $N_L$ . (A justification for our neglect of other integer variables is given in Sec. [II D 2.](#page-6-0)) Within our model, then, the interferometer has one important discrete degree of freedom, *NL*, and several continuous degrees of freedom  $A_i$ , describing the area occupied by each of the edges that are coupled to the leads, where the subscript *j* numbers the edge state. As is always the case in the quantum Hall effect, charge density on the edge translates to an area enclosed by the LL. The phase  $\theta$  is directly related to the area  $A_I$  enclosed by the interfering edge state, as delimited by the points in the constrictions where there is tunneling between the partially transmitted edge states. (The subscript *I* stands for "interfering.") Specifically, the relation is given in Eq. [\(4\)](#page-2-0) above. Alternatively, we can consider  $\theta$  as a measurable quantity (mod  $2\pi$ ), and use [\(4\)](#page-2-0), to form a precise definition of  $A<sub>I</sub>$ .

#### **B. Macroscopic energy function**

We will now formulate the way by which we will calculate [\(7\)](#page-3-0) and its dependence on *B* and  $V_G$ . Since the phase  $\theta$  depends only on what happens in the *ν*in bulk region, we find it useful to

define an energy functional  $E(N_L, A_I)$  as the total energy of the system when  $N_L$  and  $A_I$  are specified, and the energy is minimized with respect to all other variables, including the fluctuating areas  $A_j$  of any fully transmitted edge states. (The electrochemical potential  $\mu$  of the leads is here taken to be zero.)

Let us consider small variations of *B* about a given initial value  $B_0$ , at a fixed value of the gate voltage  $V_G$ . For small variations in  $N_L$ ,  $A_I$ , we may then expand the energy  $E(N_L, A_I)$  to quadratic order, and write

$$
E = \frac{K_I}{2} (\delta n_I)^2 + \frac{K_L}{2} (\delta n_L)^2 + K_{IL} \delta n_I \delta n_L, \tag{8}
$$

where  $\delta n_L$  is the deviation of the number of localized electrons from the value that would minimize the energy if there were no integer constraint on  $N_L$ , and  $\delta n_l$  is the charge, in units of the electron charge, associated with deviations in the area  $A_I$  from value that would then minimize the energy. More precisely,

$$
\delta n_L = N_L + \nu_{\rm in} \phi - \bar{q},\tag{9}
$$

where  $\bar{q}$  is the effective positive background charge, in units of |*e*|, resulting from ionized impurities in the donor layer and additional charges on the surfaces and on metallic gates, as well as any fixed charges in localized states outside the interference loop. We assume that  $\bar{q}$  depends monotonically on the gate voltage. Furthermore, for weak backscattering,

$$
\delta n_I = B(A_I - \bar{A})/\Phi_0 = n_I - \phi, \qquad (10)
$$

where  $n<sub>I</sub>$  is the charge enclosed by the interfering edge state, ignoring the charges of the localized electrons and holes.

When the gate voltage  $V_G$  is varied with *B* remaining fixed, the background charge  $\bar{q}$  and the area  $\bar{A}$  will vary. Their variation depends on the coupling of the gate to the interferometer, and we characterize it by two parameters,

$$
\beta = (B/\Phi_0)d\bar{A}/dV_G, \quad \gamma = d\bar{q}/dV_G. \tag{11}
$$

The parameter  $\beta$  describes the extent to which a variation of the gate voltage affects the area of the interferometer *AI* (and indirectly  $\phi$ ), while  $\gamma$  describes the way the gate affects the background charge in the bulk of the interferometer (and indirectly  $N_L$ ).

Note that the energy function (8) leads to an interference phase that is unchanged when *φ* varies by one. This change in *φ* can be completely compensated in the energy function by changing  $N_L$  by the integer amount  $-v_{\text{in}}$ , while  $n_I$  changes by one. The fixed value of  $\delta n_I$  means that the area  $A_I$  has not changed, but the phase  $\theta$  has changed by  $2\pi$ . Such a phase change has no effect on the value of  $e^{i\theta}$ .

#### **C. Fractional quantized Hall states**

Our considerations for the integer case can be easily extended to an edge mode separating fractional quantized Hall states of the form

$$
v_{\text{in}} = I + \frac{p}{2ps + 1}, \quad v_{\text{out}} = I + \frac{p - 1}{2s(p - 1) + 1}, \quad (12)
$$

where *p* and *s* are positive integers, and *I* is an integer  $\geq 0$ . These are filling fractions in the range  $I \le v < I + 1/2$ , and we assume that they are correctly described by the standard composite fermion picture.<sup>[30](#page-15-0)</sup> The integers *p* and  $p - 1$  are the <span id="page-6-0"></span>number of filled effective LLs for the composite fermions in the ideal FQHE states. Elementary charged quasiparticles in the region  $v_{\text{in}}$  will have a charge  $e_{\text{in}}^* = 1/(2sp + 1)$ , while quasiparticles in the region  $v_{\text{out}}$  will have a charge  $e_{\text{out}}^* =$  $1/[2s(p-1)+1]$ . We assume that the particle backscattered across the *ν*in region in the constriction is the elementary quasiparticle with charge  $e_{\text{in}}^*$ . Whether this assumption is correct in any given experiment should be checked by the results of the measurement.

As in the integer case, the local charge density  $n(\vec{r})$  may be considered the sum of a contribution from the ideal quantized Hall state and one from localized quasiparticles or quasiholes, and the difference between  $\bar{\nu}$  and the quantized nominal filling factor *ν* at point  $\vec{r}$  represents the contribution of localized charges, whose integral must be quantized in multiples of the elementary charge *e*<sup>∗</sup> corresponding to *ν*. If the electron density varies slowly near the edge of a sample, the fractional chiral edge stat[e31,32](#page-15-0) separating quantized Hall regions *ν*in and *ν*out should occur at a point were  $\bar{\nu}$  has a value somewhere in the middle between *ν*in and *ν*out.

As in the integer case, we again use a quadratic energy function of the form  $(8)$ , but now we have to modify  $(9)$  and  $(10)$  and use  $(5)$  instead of  $(4)$  to describe the relations between  $\delta n_I$ ,  $A_I$ ,  $N_L$  and  $\theta$ . Specifically, the phase  $\theta$  accumulated by an interfering quasiparticle is

$$
\frac{\theta}{2\pi} = e_{\text{in}}^* B A_I / \Phi_0 - 2N_L s e_{\text{in}}^*.
$$
 (13)

The first term is the AB phase, scaled down by the charge of the interfering quasiparticle, and the second term is the anyonic phase accumulated when one composite fermion goes around another.<sup>[33–35](#page-15-0)</sup> The statistical phase  $\theta_a$ , which appeared in Eq. [\(5\)](#page-2-0), is thus given by  $\theta_a = -4\pi s e_{\text{in}}^*$ .

It should be emphasized that Eq.  $(13)$ , which can be derived using a fermion-Chern-Simons transformation,<sup>[35](#page-15-0)</sup> should apply regardless of whether the localized charges are isolated quasiparticles of charge  $\pm e_{\text{in}}^*$  or occur in puddles where the individual quasiparticles may have lost their identity. For example, if  $v_{\text{in}} = 4/3$ , an enclosed puddle with a different filling fraction, such as  $\nu = 1$ , 2, or 7/5, must still contain a total localized charge (above the background charge corresponding to  $\nu = 4/3$ ) that is a multiple of  $e_{in}^* = 1/3$ , and the corresponding contribution to the phase on the interfering edge state is still given by the second term in (13).

An increase of the magnetic flux by one flux quantum requires, on average,  $v_{\text{in}}/e_{\text{in}}^*$  quasiparticles to maintain charge neutrality. Relation [\(9\)](#page-5-0) is correspondingly modified to

$$
\delta n_L = e_{\rm in}^* N_L + \phi v_{\rm in} - \bar{q}.\tag{14}
$$

Here  $N_L$  is the net number of quasiparticles minus quasiholes, of charge  $e_{\text{in}}^*$ , inside the interfering edge state.

The relation between the area enclosed by the interfering edge and the charge contained in the corresponding composite fermion LL—the modified version of [\(10\)](#page-5-0)—is now

$$
\delta n_I = \Delta v B (A_I - \bar{A}) / \Phi_0, \qquad (15)
$$

where  $\Delta v \equiv v_{\text{in}} - v_{\text{out}}$ . The normalizations of  $\delta n_I$  and  $\delta n_L$ have been chosen so that they are measured in units of the electron charge.

As before, in the limit of weak backscattering, the resistance oscillation will be proportional to  $\text{Re}\langle e^{i\theta}\rangle$ . Note that formulas for the fractional case reduce to those of the integer case if one sets  $s = 0$ .

#### **D. Comments on the energy function**

The previous section has defined the model we will use for analyzing the interference term [\(7\)](#page-3-0) and its dependence on *B* and *VG*. Before carrying out this calculation, we pause to make some comments on the model.

### *1. An alternative parametrization of the energy function*

The macroscopic energy function *E* may be alternatively described by an equivalent capacitor network. If we introduce electrochemical potentials  $\mu_I = \partial E/\partial(\delta n_I)$ , and  $\mu_L =$ *∂E/∂*(*δnL*), then the quadratic part of *E* may be rewritten as

$$
e^{2}E = \frac{C_{I}}{2}\mu_{I}^{2} + \frac{C_{L}}{2}\mu_{L}^{2} + \frac{C_{IL}}{2}(\mu_{I} - \mu_{L})^{2},
$$
 (16)

where

$$
K_{I} = e^{2} \frac{C_{L} + C_{IL}}{D}, \quad K_{L} = e^{2} \frac{C_{I} + C_{IL}}{D}, \quad K_{IL} = e^{2} \frac{C_{IL}}{D},
$$

$$
D = (C_{L} + C_{IL})(C_{I} + C_{IL}) - C_{IL}^{2}.
$$
(17)

The coefficients  $C_L$  and  $C_I$  may be interpreted as effective capacitances to ground for the respective conductors, while *CIL* plays the role of a cross capacitance. The effective capacitances result from a combination of classical electrostatics and quantum-mechanical energies.

An advantage of rewriting the energy in this form is that it may be easier to understand the dependencies of the capacitance coefficients on the parameters of the system. For example, we would expect the coefficients  $C_I$  and  $C_{IL}$  to be proportional to the perimeter *L* of the interferometer, if the structure of the edge is held fixed. The capacitance  $C_L$  should be proportional to the area  $\overline{A}$  of the island, if the center region is covered by a top gate with a fixed setback distance. On the other hand, we would expect  $C_L$  to vary as  $L \ln L$ , if there is no top gate and the nearest conductors are gates along the edges of the sample.

In the situation where the edge state is connected to leads in equilibrium at zero voltage, the equilibrium value of  $\mu_I$  will be zero. Then the ground-state energy will be given by  $E =$  $(C_L + C_{IL})\mu_L^2/2e^2$ , and we have  $e^2\delta n_L = \mu_L(C_L + C_{IL})$  and  $e^2\delta n_I = -\mu_L C_{IL}.$ 

#### *2. Further justification for the model*

The major simplification involved in our model is the reduction of the number of degrees of freedom in the problem. In principle, the interferometer has edge states that form one-dimensional compressible stripes and a set of localized states between these stripes that may be either empty or full. Our model reduces the problem to two degrees of freedom, *AI* and *NL*.

We neglect the degrees of freedom associated with localized states between edge states. We assume that the width *w* of the region of nonuniform electron density near the edge of the sample is small compared to the overall radius to the island. The area available for localized electrons or holes in the LL <span id="page-7-0"></span>that is partially filled in the center of the interferometer should be approximately  $\overline{A}$ , while the areas available for localized electrons or holes in any other LLs should be of order *Lw*, which is much smaller. Then the number of localized electrons or holes in any of these regions will be relatively small, and the energy cost of adding or subtracting a particle from one of them should be relatively high. Thus we may generally neglect fluctuations in these quantities at reasonably low temperatures. The fluctuations in  $N_L$  that do occur will arise normally from changes in the occupation of the innermost partially full LL.

If the magnetic field *B* or the gate voltage  $V_G$  is varied by a sufficiently large amount, we do expect to encounter discontinuous changes in the occupations of localized states other than those  $N_L$  of the innermost partially full LL. These jumps should lead to jumps in the phase  $\theta$ , which would appear as "glitches" in the interference pattern. The analysis of periodicities given above apply, strictly speaking, only in the intervals between glitches. The frequency of occurrence of glitches should roughly correspond to the addition of one electron or one flux quantum in area *Lw*, which would be rarer by a factor of  $Lw/\bar{A}$  than the oscillation frequencies we are interested in. Also, in many cases, the coupling between the interfering edge state *θ* and a particular occupation number  $N_f^h$  or  $N_f^e$  may be sufficiently small that any glitches associated with changes in that occupation number would be unobservable.

Finally, in replacing the full energy function by the macroscopic function  $E$ , we have minimized the energy with respect to all continuous variables  $n_j$  other than that of the partially transmitted edge state, i.e., we have ignored the effects of thermal fluctuations in these variables. This neglect is justified for the continuous variables, because they enter the energy in a quadratic form, so their thermal fluctuations add only a constant to the energy.

## **III. AHARONOV-BOHM AND COULOMB-DOMINATED REGIMES IN THE WEAK BACKSCATTERING LIMIT**

We now have Eq. [\(7\)](#page-3-0) for the resistance in the weak backscattering limit in terms of the interference phase *θ*. We also have Eqs. [\(4\)](#page-2-0), [\(5\)](#page-2-0), and [\(13\)](#page-6-0) for  $\theta$  in terms of the degrees of freedom  $A_I$ ,  $N_L$ , and the energy function [\(8\)](#page-5-0) for the energy and its dependence on  $B$  and  $V_G$ . In this section we make use of these expressions to calculate several thermal averages. First, we calculate the abrupt phase jump  $2\pi\Delta$  that occurs when the number of localized electrons (or quasiparticles) varies by −1. Then, we calculate the magnetic-field and gate-voltage dependencies of  $\langle e^{i\theta} \rangle$  at high temperatures, and show that in that limit the interferometer shows either AB or CD behavior, depending on the value of  $\Delta$ . Finally, we turn to the case where AB and CD behaviors mix together, and develop the tools needed to analyze this case, at low temperatures as well as high.

### **A. Continuous and abrupt phase evolution**

As the energy function is quadratic with respect to the continuous variable  $A_I$ , the average  $A_I$  is the one that minimizes the energy function. For a fixed number *NL* of localized charges, we obtain

$$
\frac{\theta}{2\pi} = e_{\text{in}}^* \phi - 2se_{\text{in}}^* N_L - \frac{K_{IL}}{K_I} \frac{1}{e_{\text{out}}^*} [e_{\text{in}}^* N_L + v_{\text{in}} \phi - \overline{q}]. \tag{18}
$$

The abrupt phase jumps  $2\pi\Delta$  associated with a change of  $N_L$  by  $-1$  can be read out from (18). For an IQHE interferometer we find

$$
\Delta = \frac{K_{IL}}{K_I} = \frac{C_{IL}}{C_L + C_{IL}}.\tag{19}
$$

When there is no bulk-edge coupling  $K_{IL} = 0$  the interference phase is unaffected by  $N_L$ . When the bulk-edge coupling is strong, the jumps are unobservable, since  $\Delta = 1$ .

For an FQHE interferometer, we have

$$
\Delta = \frac{K_{IL}}{K_I} + 2e_{\text{in}}^*s \left(1 - \frac{K_{IL}}{K_I}\right). \tag{20}
$$

Now, if  $K_{IL} = 0$ , then  $2\pi \Delta$  is the phase jump associated with the fractional statistics of the quasiparticles. When the bulk and the edge are coupled, the phase jumps reflect both the change of the area  $A_I$  caused by the introduction of quasiparticles and the fractional statistics. In the limit of strong coupling, where  $K_{IL} = K_I$ , the phase jump becomes unobservable, just as in the integer case. Now, if there is a change of  $-1$  in  $N_L$ , corresponding to the introduction of a quasihole in the bulk, the area *A<sub>I</sub>* will increase by  $(e_{\text{in}}^*/\Delta \nu)(\Phi_0/B)$ . This is the area necessary to accommodate the charge of the quasihole, and is also the area necessary for the accumulated phase to grow by  $2\pi$ .

#### **B. Magnetic-field dependence**

Next, if the parameters entering [\(8\)](#page-5-0) are known, we may calculate the thermal expectation value

$$
\langle e^{i\theta} \rangle = Z^{-1} \sum_{N_L} \int_{-\infty}^{\infty} dA_I e^{-E/T} e^{i\theta}, \qquad (21)
$$

with the partition function *Z* given by

$$
Z = \sum_{N_L} \int_{-\infty}^{\infty} dA_I e^{-E/T}.
$$
 (22)

Since *E* is a quadratic function of its variables, the integration over  $A_I$  is trivial. The sum over the discrete variable  $N_L$  can be handled by using the Poisson summation formula and taking the Fourier transform. Thus we may write

$$
\sum_{N_L=-\infty}^{\infty} = \int_{-\infty}^{\infty} dN_L \sum_{g=-\infty}^{\infty} e^{-2\pi i N_L(g-1)}.
$$
 (23)

Using this formula, one may perform the integrations over  $N_L$  in the numerator and denominator of  $(21)$ . The formulas simplify at high temperatures, where the partition function *Z* becomes independent of  $\phi$ , and we may concentrate on the numerator of  $(21)$ . We then find that the expectation value can be written in the form

$$
\langle e^{i\theta} \rangle = \sum_{g=-\infty}^{\infty} D_m e^{2\pi i m \phi}, \tag{24}
$$

where 
$$
m(g) = -\frac{v_{\text{out}}}{e_{\text{out}}^*} + g \frac{v_{\text{in}}}{e_{\text{in}}^*}
$$
, as in Eq. (6).

<span id="page-8-0"></span>The coefficients  $D_m$  may be written as

$$
D_m = (-1)^{g+1} |D_m| \exp\left[2\pi i \bar{q} \left(\frac{e_{\text{in}}^* - m}{v_{\text{in}}}\right)\right],\qquad(25)
$$

with

$$
|D_m| = e^{-2\pi^2 T/E_m}
$$
 (26)

and

$$
\frac{1}{E_m} = \frac{1}{(e_{\text{out}}^*)^2 K_I} + \frac{(g - 1 + \Delta)^2 K_I}{(e_{\text{in}}^*)^2 (K_I K_L - K_{IL}^2)}.
$$
(27)

Remarkably, Eq. (27) identifies the most dominant Fourier component of the resistance in the high-temperature limit, and displays its relation to  $\Delta$ : In the integer case and for fractions where  $m = 1$  is allowed (i.e., for fractions with  $v_{\text{in}} < 1/2$ ), if  $-1/2 < \Delta < 1/2$ , the interference is dominated by the AB component, with  $g = 1, m = 1$ . In contrast, if  $1/2 < \Delta < 3/2$ , it is dominated by the CD component, with  $g = 0$ ,  $m = 1 (v_{\text{in}}/e_{\text{in}}^*).$ 

We note that the plausible assumption of a positive cross capacitance  $C_{IL} > 0$  leads to the restriction  $0 < \Delta < 1$ . We will then find  $\Delta$  < 1/2 if and only if  $C_{IL}$  <  $C_L$ . We also remark that the energy  $E_m$  for the CD term is related to the capacitances by  $E_m = (e_{\text{in}}^*)^2 / (C_L + C_I)$ . The denominator here may be thought of as an effective capacitance resulting from the electrostatic and quantum capacitances of the combined system of the localized charges and the interfering edge state, if the edge state is disconnected from the leads.

## **C. Gate voltage dependence**

A variation of the gate voltage  $V_G$  varies the phases of the Fourier components of  $\langle e^{i\theta} \rangle$  through its effect on  $\bar{q}$  and  $\phi$  in the phases in Eqs.  $(24)$  and  $(25)$ . There are two origins to this dependence—the effect of the gate voltage on the area of the interference loop  $\overline{A}$  and its effect on the charge density in the bulk, and through it, on  $N_L$ . These two dependencies are described by the parameters  $\beta$ ,  $\gamma$  of [\(11\)](#page-5-0).

For small variations  $\delta V_G$  and  $\delta B$ , we see that  $D_m e^{2\pi i m \phi}$ varies proportional to

$$
\exp\left\{2\pi i \left[\delta V_G(\alpha_m + \beta m) + m\delta B \frac{\bar{A}}{\Phi_0}\right]\right\},\qquad(28)
$$

where the term proportional to  $\beta$  originates from the area change induced by the gate, and the term proportional to

$$
\alpha_m = \gamma (e_{\text{in}}^* - m) / v_{\text{in}} \tag{29}
$$

originates from the effect of the gate on the bulk background charge.

For the integer case, we see that lines of constant slope in the AB regime will have  $dV_G/dB = -\bar{A}/\Phi_0\beta$ , while in the CD regime, the lines of constant slope will have  $dV_G/dB =$  $f_T A/\Phi_0(\gamma - f_T \beta)$ .

We expect that applying positive voltage to a side gate should tend to increase the area  $\overline{A}$ , so that the coefficient  $\beta$ should be positive. To estimate  $\gamma$ , let us first consider a model in which there is a constant electron density in the interior of the interferometer, except for a thin region around the edge, and let us imagine that the effect of  $\delta V_G$  is to alter the location of the edge, without changing its density profile, and without changing the electron density away from the edge. In this case we would find  $\gamma = \bar{\nu}\beta$ , where  $\bar{\nu} \ge (f_T + 1/2)$  is the filling factor in the interior. In reality, we would expect that positive *δVG* will increase the average density inside, so that *γ* should be even larger. Thus we expect that the slope of the constant phase lines will be negative for the AB stripes but positive for the CD stripes.

### **D. Low temperatures**

Although at high temperatures we need only consider one Fourier component, at lower temperatures, particularly if  $\Delta$  is close to  $1/2$ , the  $g = 0$  and  $g = 1$  components may both be important. Then a color-scale map of the interference signal versus *B* and  $V_G$  will show lines of both slopes, with a resulting pattern of a checkerboard type, as seen in Fig. [2.](#page-2-0) Even if both slopes are present, however, the eye will tend to pick out only the stronger component, if there is a big difference in the amplitudes, as in Figs.  $2(b)$  and  $2(d)$ .

At still lower temperatures, higher harmonics with *g >* 2 and *g <* 0 will also appear. In general one must take into account that *Z* in the denominator of  $(21)$  depends on  $\phi$ . Let us expand *Z* as

$$
Z = \sum_{g=-\infty}^{\infty} z_g e^{2\pi i g (\nu_{\rm in} \phi - \bar{q})/e_{\rm in}^*}.
$$
 (30)

(The coefficients  $z_g$  fall off exponentially with increasing temperature, except for  $z_0$ , which is simply proportional to  $T$ .) The Fourier components of  $\langle e^{i\theta} \rangle$  will then be a convolution of the Fourier components of  $Z^{-1}$  with the Fourier coefficients obtained from the numerator of  $(21)$ , which are given by  $(25)$ and (26). We see that this does not introduce any new Fourier components into the function, but it can affect the relative weights of the different harmonics.

In the limit of low temperatures, the phase  $\theta$  becomes a sawtooth function of  $\phi$ , for fixed  $V_G$ , and we can simply evaluate the Fourier coefficients of *eiθ* . Up to a constant phase factor, we find that for the allowed values of *m*, the coefficients  $D_m$  may still be written in the form  $(25)$ , but now

$$
|D_m| = \frac{\sin(\pi \Delta)}{\pi(\Delta + g - 1)}.
$$
 (31)

We see that the CD component ( $g = 0$ ) will be largest if  $1/2 <$  $\Delta \leq 1$ , and the component (*g* = 1) will be largest if  $0 \leq \Delta$  $1/2$ , at  $T = 0$  as well as at high temperatures.

In our discussions of the temperature dependence of the interference signal, we have taken into account only classical fluctuations, ignoring quantum fluctuations, which can be important on energy scales larger than  $k_B T$ . In the FQHE case, quantum fluctuations lead to a renormalization of the tunneling amplitudes, which will typically cause the individual reflection amplitudes  $r_1, r_2$  to decrease with increasing temperature, as a power of  $1/T$ , in the weak backscattering regime.<sup>[36](#page-15-0)</sup> At high temperatures, this decrease should be less important than the exponential decrease of the interference signal arising from classical fluctuations, predicted by Eq. (26), but the power-law dependence should be taken into account at lower temperatures. If one defines a normalized interference signal by dividing the interference term by the total backscattered intensity,  $\alpha(|r_1|^2 + |r_2|^2)$ , then the low-temperature power-law

<span id="page-9-0"></span>dependence should be canceled.<sup>1</sup> Quantum fluctuations do not lead to a power-law dependence of the normalized interference signal on length of the interferometer, in the limit of vanishing temperature and vanishing source-drain voltage.<sup>[1](#page-15-0)</sup>

### **E. Two-dimensional description**

For a proper analysis of the regime where the CD and AB lines coexist, we need to introduce a two-dimensional Fourier transform of  $\delta R$  with respect to *B* and  $V_G$ , rather than the Fourier transform with respect to  $\phi$  at fixed  $V_G$ , which we have employed so far. One finds that the periodic pattern can be expanded in terms of a set of "reciprocal lattice vectors"  $\vec{G}_{gh} \equiv (G_{gh}^{(b)}, G_{gh}^{(v)})$ , where *g* and *h* are integers, with

$$
\vec{G}_{gh} = g\vec{G}_{10} + h\vec{G}_{01},
$$
\n(32)

$$
\vec{G}_{10} = 2\pi \left( \frac{\nu_{\text{in}}}{e_{\text{in}}^*} \frac{\bar{A}}{\Phi_0}, \frac{\beta \nu_{\text{in}} - \gamma}{e_{\text{in}}^*} \right)
$$
(33)

$$
\vec{G}_{01} = 2\pi \left( -\frac{v_{\text{out}}}{e_{\text{out}}^*} \frac{\bar{A}}{\Phi_0}, \frac{\gamma - \beta v_{\text{out}}}{e_{\text{out}}^*} \right), \tag{34}
$$

and

$$
\delta R(B, V_G) = \sum_{gh} R_{gh} e^{i \left( G_{gh}^{(b)} \delta B + G_{gh}^{(v)} \delta V_G \right)}. \tag{35}
$$

The reality of  $\delta R$  requires that  $R_{gh} = R^*_{-g,-h}$ .

The set of reciprocal lattice vectors may be derived by first removing the restriction that *NL* is an integer. Regardless of the values of  $K_I, K_L, K_{IL}$ , the energy can then be minimized by choosing  $A_I$  and  $N_L$  so that  $\delta n_I = \delta n_L = 0$ , using [\(15\)](#page-6-0) and [\(14\)](#page-6-0). If we then calculate changes in  $\theta$  using [\(13\)](#page-6-0), we find that  $\delta \theta = G_{11}^{(b)} \delta B + G_{11}^{(v)} \delta V_G$ , while  $\delta N_L = -(G_{10}^{(b)} \delta B +$  $G_{10}^{(v)} \delta V_G$  //2 $\pi$ , with  $\vec{G}_{gh}$  defined as in (32)–(34). Here, we have used the relations  $\Delta v = e_{\text{in}}^* e_{\text{out}}^*$  and  $2s = (e_{\text{out}}^* - e_{\text{in}}^*)/\Delta v$ .

In the limit of weak backscattering, the only reciprocal lattice vectors with nonzero amplitudes have  $h = \pm 1$ . For  $h =$ 1, the coefficients  $R_{gh}$  may be related to the coefficients  $D_m$ defined previously, with  $R_{g,1} \propto r_1 r_2 D_m$ , where *m* is related to *g* by Eq. [\(6\)](#page-2-0) and  $r_1, r_2$  are the bare reflection amplitudes at the two constrictions. For  $h = -1$ , the coefficients are the complex conjugates of *R*−*g,*1.

When one goes beyond weak backscattering, as discussed below, one finds harmonics at reciprocal lattice vectors which are arbitrary sums of the ones present in the weak backscattering limit. Thus, one may obtain contributions at all integer values of  $h$ , including  $h = 0$ .

Using the two-dimensional description, we may readily extend our analysis to the situation where one cannot neglect the dependence of the secular area  $\overline{A}$  on the magnetic field *B*. In this case, we should also take into account the change in the "background charge"  $\bar{q}$  resulting from the change in  $\bar{A}$ . We define two dimensionless parameters,

$$
\lambda = -\frac{B}{\bar{A}} \frac{\partial \bar{A}}{\partial B}, \quad \eta = -\frac{\Phi_0}{\bar{A}} \frac{\partial \bar{q}}{\partial B}.
$$
 (36)

Then the formulas for the fundamental reciprocal lattice vectors should be replaced by

$$
\frac{\vec{G}_{10}}{2\pi} = \left[ \left( \frac{\nu_{\text{in}}(1-\lambda) + \eta}{e_{\text{in}}^*} \right) \frac{\bar{A}}{\Phi_0}, \frac{\beta \nu_{\text{in}} - \gamma}{e_{\text{in}}^*} \right],\qquad(37)
$$

$$
\frac{\vec{G}_{01}}{2\pi} = \left[ -\left(\frac{v_{\text{out}}(1-\lambda) + \eta}{e_{\text{out}}^*}\right) \frac{\bar{A}}{\Phi_0}, \frac{\gamma - \beta v_{\text{out}}}{e_{\text{out}}^*} \right].
$$
 (38)

If the field *B* is varied while the gate voltage  $V_G$  is held fixed, the field periods associated with the AB term  $(g,h) = (1,1)$ and the CD term  $(g,h) = (0,1)$  are given, respectively, by

$$
\bar{A}(\Delta B)_{AB} = \frac{\Phi_0}{(1 - \lambda) \left(\frac{v_{\text{in}}}{e_{\text{in}}^*} - \frac{v_{\text{out}}}{e_{\text{out}}^*}\right) + \eta \left(\frac{1}{e_{\text{in}}^*} - \frac{1}{e_{\text{out}}^*}\right)},\quad(39)
$$

$$
\bar{A}(\Delta B)_{\rm CD} = -\frac{e_{\rm out}^* \Phi_0}{\eta + v_{\rm out}(1 - \lambda)}.
$$
 (40)

If  $\eta \neq 0$ , the two periods will generally be incommensurate. Then when the magnetic field is varied at constant gate voltage, the resistance will not be a periodic function of *B*, but rather quasiperiodic. To obtain a periodic variation, one must vary *B* and *VG* simultaneously, along a line of appropriate slope.

As a simple example, let us assume that  $\bar{A}(B,V_G)$  is determined by a contour in the zero-field electron density  $n(\vec{r})$ , where  $n\Phi_0/B = (v_{\text{in}} + v_{\text{out}})/2$ , and let us assume that  $\bar{q}$  is equal to the integral of this density inside the area  $\bar{A}$ . Then we find

$$
\eta = \frac{\lambda(\nu_{\text{in}} + \nu_{\text{out}})}{2},\tag{41}
$$

$$
\lambda = \frac{1}{\bar{A}} \oint \frac{n(\vec{r}) dr}{|\nabla n|},\tag{42}
$$

where the integral is around the perimeter of the area  $\overline{A}$ . We see that  $\eta$  and  $\lambda$  will vanish in the limit where the length scale for density variations at the edge is small compared to the radius of the island (assuming that the density in the bulk is not too close to density at the interfering edge state).

#### **IV. INTERMEDIATE BACKSCATTERING**

If one goes beyond the lowest order in the backscattering amplitudes  $r_1$  and  $r_2$ , the above analysis must be modified in several respects. In this section we confine ourselves to the IQHE case; we come back to the FQHE in the next section, for the regime of strong backscattering.

The most obvious change from the weak backscattering limit is that the interference contribution to the resistance  $R_D$  is no longer simply proportional to  $\text{Re}[r_1 r_2^* e^{i\theta}]$ . To be specific, let us consider the case of symmetric constrictions, so that  $r_1 = r_2$ . We may write  $R_D^{-1} = (f_T + 1 - P_R)(e^2/h)$ , where  $0 < P_R <$ 1 is the probability that an incident electron in the partially transmitted edge state will be reflected by the interferometer region. If we continue to define *θ* as the phase accumulation around the interferometer loop for an electron at the Fermi energy, then the full expression for  $P_R$  is

$$
P_R = 2|r_1|^2 \frac{1 + \cos \theta}{1 + |r_1|^4 + 2|r_1|^2 \cos \theta}.
$$
 (43)

If we expand this in powers of  $r_1$ , we find terms of order  $|r_1|^4$  multiplying  $\cos^2 \theta$ , etc., which we may understand as contributions from electrons that undergo multiple reflections and therefore traverse the circuit more than once. Such terms will add additional harmonics of  $e^{2\pi i \phi}$  to the reflection coefficient, and in principle all harmonics will be present. However, the underlying period will not be affected. Moreover, <span id="page-10-0"></span>at least at high temperatures, the higher harmonics should fall off faster than the principal AB component ( $\propto e^{2\pi i \phi}$ ) or the principal CD component  $(\alpha e^{-2\pi i f_T \phi})$  and should not be very noticeable.

In the presence of a significant reflection probability, one should also take into account the fact that in this case the number of electrons enclosed by the partially transmitted edge state is no longer precisely equal to  $\theta/2\pi$ . This follows from the Friedel sum rule, which states that  $\rho(\epsilon)$ , the density of states for the LL inside the interferometer at energy  $\epsilon$ , may be written as

$$
\rho(\epsilon) = \frac{1}{\pi} \frac{\partial (\eta_+ + \eta_-)}{\partial \epsilon},\tag{44}
$$

where  $\eta_{\pm}$  are the phase shifts, derived from the eigenvalues  $e^{2i\eta_{\pm}}$  of the 2 × 2 *S* matrix for transmission through the interferometer. Explicitly, the eigenvalues are given by

$$
e^{2i\eta_{\pm}} = \frac{(1-|r_1|^2)e^{i\theta/2} \pm i|r_1|(e^{i\theta}+1)}{1+|r_1|^2e^{i\theta}},
$$
(45)

and the phase shifts are required to be continuous functions of the energy  $\epsilon$ . The reflection probability (43) may then be written as  $P_R = \sin^2(\eta_+ - \eta_-)$ . For  $|r_1|^2 \neq 0$ , Eq. (45) gives an oscillatory contribution to the phase shifts and an oscillatory contribution to the density of states. Since the electron number *n<sub>I</sub>* is the integral of  $\rho(\epsilon)$  up to the Fermi energy, it will also acquire an oscillatory part. Specifically we may write

$$
n_I = \pi^{-1}(\eta_+ + \eta_-) + \text{const} = (2\pi)^{-1}\theta + f(\theta), \qquad (46)
$$

where the phase shifts are evaluated at the Fermi energy, and  $f(\theta)$  is periodic, with period  $2\pi$ .

The oscillatory contribution to  $n<sub>I</sub>$  will also be manifest when one varies the magnetic field, the gate voltage, or the electrochemical potential  $\mu$ . For an interacting system, where the number of electrons  $n_I$  associated with the interfering edge state is coupled to other variables, such as  $N_L$ , or even to continuous variables such as the number of electrons in fully transmitted edge states, an oscillatory component of  $n_I$ will lead to an additional oscillatory component to the energy *E*, which should be taken into account when evaluating the thermal average of  $P_R$ . Again, we see that these effects can lead to additional oscillatory contributions at harmonics of the basic periods, giving rise to nonzero amplitudes at arbitrary reciprocal lattice vectors  $G_{gh}$ , but they should not change the fundamental frequencies  $G_{10}$  and  $G_{01}$ .

We can treat the case of intermediate (or strong) backscattering within our general model if we make a few modifications of the definitions. We continue to use the energy formula [\(8\)](#page-5-0), with the definitions [\(4\)](#page-2-0) and [\(9\)](#page-5-0) for  $\theta$  and  $\delta n_L$ . We continue to define  $\delta n_I \equiv n_I - \phi$ , as in [\(10\)](#page-5-0), but we can no longer equate this to  $B(A_I - \overline{A})/\Phi_0$ . Instead, we must compute  $n_I$  using (46). Finally, we must calculate  $\langle P_R \rangle$  by averaging [\(43\)](#page-9-0) with the weight  $e^{-E/T}$ , integrating over  $A_I$ , and summing over  $N_L$ .

#### **V. STRONG BACKSCATTERING**

It is interesting to explore the behavior of the interferometer at low temperatures in the limit of strong backscattering, where the amplitude  $r_1$  is close to unity. For the case  $r_1 = r_2$ , when  $\theta$  is an odd integer multiple of  $\pi$  a resonant tunneling occurs,

and  $P_R = 0$ . Then, for noninteracting electrons, at large  $r_1$ , we would find that the reflection probability  $P_R$  is close to unity most of the time, but there would be a series of values of the magnetic field, or of the gate voltage, where in a narrow interval,  $P_R$  drops to zero. The actual vanishing of  $P_R$  is special to the case where  $r_1 = r_2$ , but even for an asymmetric case, one would find reductions in  $P_R$  in the vicinity of the points where  $\theta$  is an odd multiple of  $\pi$ .

We now analyze the effect of interactions between electrons on these transmission resonances, and in particular on the flux spacing  $\Delta \phi$  between transmission resonances. Interestingly, we find that this spacing is different for interferometers in the AB and CD regimes.

In the limit of strong backscattering the charge enclosed in the  $v_{\text{in}}$  area is almost quantized in units of  $e_{\text{out}}^*$ , and the value of  $n<sub>I</sub>$  increases with  $A<sub>I</sub>$  in a series of almost-step functions. It is therefore convenient to use the essentially discrete variable  $n_I$  rather than  $A_I$  as the variable in our energy functional. The condition for a transmission resonance, that *θ* is an odd multiple of  $\pi$ , is also the condition for a degeneracy of the energy for two consecutive values of the charge on the interfering edge. We shall take advantage of the discreteness of  $n<sub>I</sub>$  to explore how this affects the magnetic-field spacings between resonances.

We start with the integer quantum Hall regime. Let  $N<sub>o</sub>$  =  $n_I + N_L$  be the total number of electrons in the higher LLs enclosed by the (almost closed) interfering edge channel, excluding electrons in the  $f_T$  filled LLs that correspond to the totally transmitted channels. The energy of the system is then

$$
E(N_o, N_L) = \frac{K_I}{2} (N_o - N_L - \phi)^2
$$
  
+  $K_{IL}(N_o - N_L - \phi)[N_L + (f_T + 1)\phi - \bar{q}]$   
+  $\frac{K_L}{2} [N_L + (f_T + 1)\phi - \bar{q}]^2$ . (47)

An increase of  $\phi$  by one decreases  $N_L$  by  $(f_T + 1)$  and increases  $N<sub>o</sub>$  by  $f<sub>T</sub>$ . Resonant transmission occurs when there is a vanishing energy cost for adding one electron to the closed edge, that is, a vanishing energy cost for varying *No* by one while keeping *NL* fixed. Degeneracy points where *NL* changes by  $\pm 1$  while  $N<sub>o</sub>$  is fixed will generally not lead to resonances, even though  $n_I$  changes by  $\mp 1$  at such points. Although the  $\theta$  will technically pass through an odd multiple of  $\pi$  in this process, one expects that these transitions will generally happen discontinuously, so there is no point at which the resonance could be observed. Points where  $N_L$  and  $N_o$ increase simultaneously do not involve a change in  $n<sub>I</sub>$  and do not lead to transmission resonances.

In the extreme AB limit, where  $K_{IL} = 0$ , there are degeneracy points where  $E(N_o, N_L) = E(N_o + 1, N_L + 1)$  separated on the  $\phi$  axis by spacings  $\Delta \phi = 1/(f_T + 1)$ . These points do not, however, lead to resonances, since they involve a change in *NL*. Degeneracy points that do lead to resonances occur when  $E(N_o, N_L) = E(N_o + 1, N_L)$ , and the spacings between those is  $\Delta \phi = 1$ , the flux period that characterizes also the weak backscattering regime of the AB limit.

In the extreme CD regime,  $K_I = K_{IL}$ , and stability requires  $K_L > K_I$ . Then jumps of  $N_L$  are separated from jumps of  $N<sub>o</sub>$ . In an interval where  $\phi$  increases by 1, there will be  $f<sub>T</sub>$ 

<span id="page-11-0"></span>resonant events where  $N<sub>o</sub>$  decreases by one, while  $N<sub>L</sub>$  is fixed, and  $(f_T + 1)$  separate events where  $N_L$  increases by one while  $N_o$  is fixed. The resonances are thus separated by  $\Delta \phi = 1/f_T$ . Again, this is the flux period that characterized the CD regime in the weak backscattering limit.

The difference in  $\Delta \phi$  between the AB and CD limits characterizes also the fractional case. In this case the bulk accommodates  $N_L$  quasiparticles of charge  $e_{\text{in}}^*$ , and the total charge in the *ν*<sub>in</sub> region is quantized in units of  $e_{out}^*$ . The charge on the interfering edge is given by

$$
n_I = N_o e_{\text{out}}^* - N_L e_{\text{in}}^*.
$$
\n<sup>(48)</sup>

Then, the energy functional becomes

$$
E(N_o, N_L) = \frac{K_I}{2} (e_{\text{out}}^* N_o - e_{\text{in}}^* N_L - \Delta \nu \phi)^2 + K_{IL} (e_{\text{out}}^* N_o - e_{\text{in}}^* N_L - \Delta \nu \phi) \times (e_{\text{in}}^* N_L + \nu_{\text{in}} \phi - \bar{q}) + \frac{K_L}{2} (e_{\text{in}}^* N_L + \nu_{\text{in}} \phi - \bar{q})^2.
$$
 (49)

In the CD limit,  $K_{IL}/K_I = 1$ , and the number of transmission resonances that occur while  $\phi$  changes by one is equal to  $v_{\text{out}}/e_{\text{out}}^*$ . This leads to  $\Delta \phi = e_{\text{out}}^*/v_{\text{out}}$ . The leading component in the Fourier transform of  $P_R(\phi)$  would then correspond to the  $g = 0$  component of [\(6\)](#page-2-0), just as in the weak backscattering limit.

In the extreme AB limit, where  $K_{IL} = 0$ , the structure of transmission resonances is more complicated, due to the difference between the elementary charges  $e_{in}^*$  and  $e_{out}^*$ . Just as in the weak backscattering case for the FQHE at  $K_{IL} = 0$ , there is no single dominant value of *g*. In the case of weak backscattering, this occurs because  $\Delta = 2se_{\text{in}}^* \neq 0$ , according to Eq. [\(20\)](#page-7-0). Here we note that  $e_{\text{out}}^* - e_{\text{in}}^* = 2se_{\text{in}}^* e_{\text{out}}^*$ .

Over all, we see that in the limit of strong backscattering, in the CD regime, the number of peaks in the transmission probability as we increase *B* by one flux quantum is the same number  $v_{\text{out}}/e_{\text{out}}^*$  as we obtained in the weak backscattering regime, consistent with the prediction that the period of the CD oscillations would not change as we vary  $r_1$ . The strong backscattering limit may also be understood as a Coulomb blockade effect: Maxima in the transmission probability occur at points where the system consisting of the localized states and the almost totally reflected edge state is about to change from one integer value to another.

Typically, the reflection coefficient  $r_1$  should increase from near zero to near unity as one decreases the electron density in the constrictions through the range where the filling factor *νc* at the center of the constriction decreases from slightly below *ν*in to slightly above *ν*out. For an ideal constriction, the variation in  $r_1$  should be smooth and monotonic. In real constrictions, however, the variation may be more complicated, as the Fermi level may pass through one or more resonances due to tunneling through localized states in the constriction.

Our discussion of the variation in  $r_1$  should also apply if *νc* is varied by changing the magnetic field *B* rather than by changing a gate voltage at the constriction. Again, the field periods for the AB and CD oscillations should remain fixed as long as  $v_{\text{out}}/e_{\text{out}}^*$  does not change. However, the

parameter  $\Delta$  which governs the relative strengths of the AB and CD contributions could conceivably change as the other parameters are varied.

Under some circumstances, if there is a large region of intermediate electron density within a constriction, the number of localized states in the constriction may become so large that there is a large density of states at low energies associated with rearrangements of electrons in these states. Then, backscattering through the constriction could become incoherent, either because of inelastic scattering from the low energy modes, or because the path length for tunneling is changed randomly due to thermally excited rearrangements of the localized states. We assume that this does not happen in the system of interest.

## **VI. MODEL WITH MULTIPLE EDGE STATES**

In order to better understand how the presence of multiple edge states may affect the parameters entering the energy function  $(8)$ , we discuss here some simplified models which may illustrate the physics.

We consider the integer case, with  $f_T$  fully transmitted edge states. We define  $\delta n_i$  to be the charge fluctuation associated with a fluctuation in area of the *i*th edge state, for  $1 \leq i \leq n$ *N*, where  $N = f_T + 1$ , while  $\delta n_i = \delta n_L$ , for  $i = N + 1$ . The partially reflected edge state has  $i = N$ , so  $\delta n_I = \delta n_N$ .

We may now write the quadratic part of the energy in the form

$$
E = \sum_{ij} \frac{\kappa_{ij}}{2} \delta n_i \delta n_j,
$$
 (50)

where the sums go from 1 to  $N + 1$ . We assume that the coupling constants  $\kappa_{ij}$  are known, and we wish to find the values of the coupling constants  $K_L, K_I, K_{IL}$  which entered our earlier computations. We wish to specify the values of  $δn<sub>L</sub>$ and  $\delta n_I$ , and minimize the energy with respect to the other variables. This means that for  $1 \leq j \leq N - 1$ , we have

$$
\sum_{i} \kappa_{ji} \delta n_i = 0. \tag{51}
$$

The resulting energy will be quadratic in  $\delta n_I$  and  $\delta n_L$ , and the coefficients may be identified with  $K_I$ ,  $K_L$ , and  $K_{IL}$ .

We illustrate further with two examples. In our first model, we consider a situation where

$$
\kappa_{ij} = U + \kappa_1 \delta_{ij},\tag{52}
$$

for  $1 \leq i, j \leq N$ , and

$$
\kappa_{ij} = \kappa_L, \quad \text{for} \quad i = j = N + 1,
$$

 $\kappa_{ij} = V$ , if either *i* or  $j = N + 1$ , but  $i \neq j$ .

In this model, the interaction between the edge states is entirely determined by the total edge charge  $\sum_{j \leq N} n_j$ , and the interaction with  $N_L$  involves only that charge. After some straightforward algebra, one obtains the results

$$
K_I = \kappa_I + \tilde{U}, \quad K_{IL} = \tilde{V}, \tag{53}
$$

<span id="page-12-0"></span>where

$$
\tilde{U} \equiv U - \frac{f_T U^2}{\kappa_1 + f_T U},\tag{54}
$$

and  $\tilde{V} = V \tilde{U} / U$ . We see from these results that  $K_{IL}/K_I =$  $\hat{V}/(\kappa_1 + \hat{U})$ . If  $V \le U$  and  $f_T > 0$ , this ratio is necessarily less than 1*/*2, so the model will be in the AB regime. For  $f_T = 0$ , the model leads to the CD regime if and only if  $\kappa_1$  +  $U < 2V$ .

The second model we consider is the opposite extreme, where edges are coupled only to their nearest neighbors. We choose the diagonal coupling constants  $\kappa_{ij}$  as the previous model, while for off-diagonal couplings we choose  $\kappa_{ij} =$  $\kappa_{12}$ , if  $|i - j| = 1$ , and  $\kappa_{ij} = 0$  otherwise. Now, we find that couplng to the fully transmitted edges renormalizes the coefficient  $K_I$  but has no effect on  $K_L$  and  $K_{IL}$ , which remain equal to  $\kappa_L$  and  $\kappa_{12}$ , respectively. In the case  $f_T = 1$ , we find

$$
K_I = \kappa_1 - \kappa_{12}^2 / \kappa_1. \tag{55}
$$

The value of  $K_I$  will be reduced further with increasing  $f_T$ , but the value remains finite in the limit of large  $f<sub>T</sub>$ , where one finds

$$
K_I \to \frac{\kappa_1}{2} + \frac{\left(\kappa_1^2 - 4\kappa_{12}^2\right)^{1/2}}{2}.\tag{56}
$$

We see that in this model,  $K_I$  is reduced by up to a factor of 2 as a result of coupling to additional edges. Stability of the model, in the limit of large  $f_T$ , requires that  $\kappa_{12}/\kappa_1 < 1/2$ , and we see that  $K_{IL}/K_I$  < 1. At the same time, if  $2/5 < \kappa_{12}/\kappa_1 < 1/2$ , the ratio  $K_{IL}/K_I$  will be greater than  $1/2$ , for sufficiently large  $f_T$ , so the system may be pushed from AB into the CD regime. Of course, the CD regime could be reached more easily if the model is modified so that the coupling  $\kappa_{N,N+1}$ between the localized charge and the partially reflected edge state is made larger than the other coupling energies, or if the diagonal element  $\kappa_{NN}$  is made smaller than the coefficients  $\kappa_{ii}$ for the fully transmitted edge states.

For a uniform edge of length *L*, we expect that the constants *κ<sub>ij</sub>* should be proportional to  $1/L$ , for  $1 \le i, j < N$ . If we write

$$
\kappa_{ij} = \frac{2\pi\hbar}{e^2 L} v_{ij},\tag{57}
$$

then coefficients  $v_{ij}$  have the dimensions of velocity. If we can neglect the response of all other degrees of freedom in the system, then fluctuations in the densities  $\delta n_i$  for the edge modes will propagate with velocities that are given by the eigenvalues of the velocity matrix  $v_{ij}$ . In actuality, however, the situation is more complicated, as coupling to charges in localized states may reduce the coupling constants  $\kappa_{ij}$  and the propagation velocities by different amounts. The propagation velocities are only affected by rearrangements of charge or polarization that can take place on time scale faster than the time  $L/v$  for a pulse to propagate around the interferometer, whereas the constants  $\kappa_{ij}$  entering our formulas are defined for fluctuations on a longer time scale.

## **VII. CONNECTION TO PREVIOUS THEORETICAL AND EXPERIMENTAL WORKS**

Oscillations in the transport properties of quantum Hall devices, associated with interference effects, were already observed in the 1980s, in both IQHE and FQHE regimes.<sup>[20](#page-15-0)</sup> The possible importance of Coulomb blockade effects $37$  in these experiments, and of fractional statistics $38$  for the FQHE situation, was noted by theorists around that time. Interpretation of the early experiments was difficult, however, as the interfering paths were not the result of a deliberate construction but were, presumably, the result of random fluctuations in the doping density, whose geometry was not known. In a typical case, one might see oscillations in the resistance of a micrometer-scale Hall bar, on the high-field side of a quantized Hall plateau, which might be attributed to backscattering through a "dot" or an "antidot" inclusion, where the electron density was higher or lower than in the surrounding electron gas. The strength of tunneling into and out of the dot or antidot was generally assumed to be weak, and the oscillations were associated with resonances as additional electrons or quasiparticles were added to the inclusion. $39$  In later years, improved experiments were carried out using fabricated antidots with controlled areas, in which one could investigate systematically the dependence on magnetic field and on electron density, controlled by a back gate. $40$ 

Quantum Hall interferometers with the Fabry-Pérot geometry studied in the present paper have been explored experimentally by several groups. In several early works, Coulomb blockade effects in a dot *weakly* coupled to leads were studied, in a region with several filled LLs.<sup>41,42</sup> The crossover between the AB and CD regime for a weakly coupled dot was analyzed in Ref. [43.](#page-15-0) Both integer and fractional quantum Hall interferometers in the absence of charging effects were discussed in Ref. [1.](#page-15-0)

In an earlier experiment, $44$  a strong dependence of the magnetic-field period  $\Delta B$  on the constriction filling factor was found but interpreted in terms of a magnetic-field-dependent interferometer area. In a reanalysis $45,46$  of that experiment, it was pointed out that, under the assumption of a magneticfield-independent interferometer area, the data agree with  $\Delta B \sim 1/v_{\rm in}.$ 

More recently, several groups have conducted systematic investigations of interferometers of different sizes, with and without top gates, in which they could set the filling factor in the constriction independently of the density in the bulk, and data has been collected as a continuous function of both magnetic-field and side-gate voltage.<sup>13,16</sup> The AB regime, the CD regime, and the intermediate regime were all observed in these experiments. In the CD regime, when lines of equal  $R_D$  were plotted in the  $B-V_G$  plane, they were found to have positive slope for  $v_{\text{out}} \neq 0$ , or zero slope for  $v_{\text{out}} = 0$ . The CD flux period, in the integer case, was found to be  $\Delta \phi =$ 1*/ν*out, independent of the strength of the backscattering. The AB regime, observed in the IQHE, was characterized by lines of equal  $R_D$  that had a negative slope in the  $B-V_G$ plane and flux periodicity of  $\Delta \phi = 1$ . Intermediate regimes, where AB and CD behaviors combined together, were also observed, giving a checkerboard pattern of the type seen in Fig. [2\(c\).](#page-2-0)

<span id="page-13-0"></span>In the fractional case a flux periodicity of  $\Delta \phi = 1/v_{\text{out}}$  was observed in the cases  $(v_{\text{in}}, v_{\text{out}}) = (\frac{1}{3}, 0)$  and  $(\frac{4}{3}, 1)$ , where  $v_{\text{out}}$ is an integer and  $v_{\text{in}}$  is a fraction. In the case of  $(\frac{2}{5}, \frac{1}{3})$ , a period of  $\Delta \phi = e_{\text{out}}^*/v_{\text{out}} = 1$  was observed.<sup>[16](#page-15-0)</sup>

In an earlier work, $6$  in which two of us analyzed the interference patterns in a Fabry-Pérot interferometer, a parameter  $\Delta_{x}/\Delta$  characterizing the strength of bulk-edge coupling was introduced. In the present notation, it corresponds to the ratio  $K_{IL}/K_I$ . Here, we have gone beyond the approach of Ref. [6](#page-15-0) by studying the directions of lines of constant phase and the temperature dependence of the interference terms, and by allowing for arbitrary strength of backscattering.

A first-principles approach to the study of interferometers was described in Ref. [47.](#page-16-0) Possibly due to the approximations chosen in that approach, an influence of Coulomb interactions on the magnetic field period of resistance oscillations was not found.

A situation in which the area of the interfering loop is small compared to the lithographic area, and where it is highly dependent on the magnetic field, was discussed in Ref. [48.](#page-16-0) In this parameter regime, the coefficient  $\lambda$ , defined in our Eq. [\(42\)](#page-9-0), can be larger than 2, so  $(1 - \lambda)^{-1}$  can be negative, with a magnitude smaller than 1. This would cause the AB constantphase lines to have a reversed slope, and a period smaller than one flux quantum. However, under this assumption, the magnetic-field period would vary continuously, rather than being quantized at a flux quantum divided by an integer, so this mechanism does not seem to explain the experimental findings. $13,16$  Also, this would not explain the simultaneous appearance of AB and CD lines, as observed in several cases.

The influence of anyonic statistics on magnetic-field periodicities of Fabry-Pérot interferometers was discussed in Ref.  $49$ , although the results obtained there disagree in some cases with our findings.

Observations of a magnetic-field superperiod, corresponding to an addition of five flux quanta to the interferometer area have been reported in Refs. [9,10](#page-15-0) and [50](#page-16-0) for a sample in which the bulk is in a quantized Hall state with  $\nu = 2/5$ , while the constrictions have a filling fraction of 1*/*3. We do not have an explanation for these results. However, we do not accept the theoretical explanation put forth in these papers or in Ref. [49.](#page-16-0) Although we agree with the arguments which show that addition of five flux quanta should leave the interference pattern unchanged, we believe this should also hold for the addition of a single flux quantum, in the physical model presented in these papers.<sup>51</sup>

## **VIII. DISCUSSION AND CONCLUSIONS**

In this paper, we have presented a general framework for discussing the electronic transport in a quantum Hall Fabry-Pérot interferometer. Our aim was to understand the oscillatory dependence of the interferometer resistance  $R_D$  on the magnetic field *B* and voltage applied to a side gate  $V_G$ , when these parameters are varied by an amount large enough to change the number of flux quanta or the number of electrons by a finite amount, but small enough so that there is not a large fractional change in either the flux or the electron number. A central assumption was that the resistance arises from the partial reflection of one quantum Hall edge state in the two constrictions. We also restricted our analysis to the integer quantum Hall states or a subset of fractional states, where all modes at a given edge propagate in the same direction. Our understanding of the physics of the problem was described in general terms in the introduction, Sec. [I,](#page-0-0) and in detail in the body of the paper. In this summary we focus on the results we obtained.

We found that  $\delta R$ , the oscillatory part of  $R_D$ , is, in general, a two-dimensional periodic function in the plane of *B* and  $V_G$ . It is useful to describe this function in terms of its two-dimensional Fourier transform, which means that we should specify a set of reciprocal lattice vectors  $G_{gh}$  and the associated amplitudes *Rgh*, where *g,h* are arbitrary integers, and  $G_{gh} = gG_{10} + hG_{01}$ . Explicit formulas for the reciprocal lattice basis vectors  $G_{10}$  and  $G_{01}$  were given in Sec. [III E,](#page-9-0) in terms of the smoothly varying secular area  $\overline{A}$  enclosed by the interfering edge mode, the filling factors *ν*in and *ν*out of the quantum Hall states separated by this edge mode, and parameters  $\beta$ , $\lambda$ , $\gamma$ , $\eta$  describing the derivatives of  $\overline{A}$  and the enclosed "background charge"  $\bar{q}$  with respect to  $V_G$  and *B*. Our most general expression for *δR* is

$$
\delta R(B, V_G) = \sum_{gh} R_{gh} e^{i(G_{gh}^{(b)} \delta B + G_{gh}^{(v)} \delta V_G)}, \tag{58}
$$

with basis vectors given by  $(37)$  and  $(38)$ . However, in cases where the radius of the interferometer is large compared to the widths of the density transition regions at the edges, one may be able to neglect the magnetic-field dependence of  $\overline{A}$  and  $\overline{q}$ , in which case  $\lambda$  and  $\eta$  may be set equal to zero. Then the basis vectors  $G_{10}$  and  $G_{01}$  are given by the simpler expressions [\(33\)](#page-9-0) and [\(34\)](#page-9-0).

For the remainder of this summary, we shall limit ourselves to the case  $\lambda = \eta = 0$ . Then, if  $V_G$  is held fixed, we find that  $\delta R$ is a periodic function of the magnetic field, with a fundamental period corresponding to the addition of one flux quantum to the area  $\overline{A}$ . However, the fundamental period may not have the largest Fourier amplitude, so the most visible oscillations may correspond to a harmonic, with a period that is the fundamental period divided by an integer.

For noninteracting electrons, in the integral quantized Hall effect, the observed interference pattern will reflect the fundamental AB period, where the phase increases by  $2\pi$ when the dimensionless magnetic flux  $\phi = BA/\phi_0$  changes by one, due to variation of *B* or of  $V_G$  or both. In our current notation, this means that nonzero Fourier components *Rgh* will correspond to reciprocal lattice vectors where  $g = h$ . In the case of weak backscattering at the constrictions, or at high temperatures, the oscillations are simply sinusoidal, and the dominant contributions are  $R_{11}$  and its conjugate  $R_{-1,-1}$ . On a a color-scale map of  $\delta R$  in the  $B-V_G$  plane, AB oscillations would appear as a series of parallel stripes with negative slope. For stronger backscattering, at low temperatures, we may get higher Fourier components due to multiple scattering events across the two constrictions.

In the case of weak backscattering, Fourier components at additional reciprocal lattice vectors can arise from electronelectron interactions. For the IQHE, this is due to the Coulomb interaction between electrons on the interfering edge state and localized electrons or holes which exist in the bulk of the interferometer. Because the number of localized particles is required to be an integer, the net number of localized particles  $N_L$  will jump periodically, as *B* or  $V_G$  is varied. Interactions with the edge then cause small variations  $\delta A_I$  in the area *AI* enclosed by the interfering edge state, which will cause the actual number of flux quanta enclosed by  $A_I$  to fluctuate about the nominal value  $\phi$ , and thus lead to an additional modulation of the interference phase. For FQHE states, there is an additional jump  $\theta_a$  in the interference phase, arising from the fractional statistics, whenever there is a change in the number of localized quasiparticles.

If the Coulomb coupling between  $N_L$  and the edge-state charge is sufficiently strong, one finds that the dominant terms in the Fourier expansion have  $g = 0$ , both for the IQHE and the FQHE. In this limit, the color-scale map will show a series of stripes which have a positive slope and  $\Delta \phi = e_{\text{out}}^*/v_{\text{out}}$ , except when  $v_{\text{out}} = 0$ , in which case the stripes will be horizontal on a  $B$ - $V_G$  plot.

In between the AB and CD limits, the two sets of stripes occur simultaneously, and a map of *δR* will show a checkerboard pattern, as seen in Fig. [2](#page-2-0) above. The absolute strengths of the various Fourier coefficients will depend on the backscattering amplitudes in the individual constrictions and on the temperature, as well as on three energy parameters, which we denote  $K_I, K_L, K_{IL}$ . At high temperatures, the Fourier amplitudes will fall off exponentially with *T* with varying rates, so generally a single pair of Fourier amplitudes will dominate at large *T*. This may be either the AB term  $(g = h = \pm 1)$  or the CD term  $(g = 0, h = \pm 1)$ . Then, for a fixed gate voltage, the interference pattern in *δR* will be a simple sine function of magnetic field, with either the AB or CD period.

At lower temperatures, where many Fourier components maybe present the situation is more complicated. We discuss here the limit of weak backscattering, where *h* is limited to  $h = \pm 1$ . Then, at low temperatures, one finds that the phase *θ* of the interference path is a sawtoothed function of the magnetic field, varying linearly with *B* most of the time, but with periodic jumps by an amount  $2\pi\Delta$ , which occur each time the number of localized quasiparticles  $N_L$  changes by −1. There will be *ν*in*/e*<sup>∗</sup> in equally spaced phase jumps per flux quanta change in the loop, which give rise to Fourier components of  $\langle e^{i\theta} \rangle$  with arbitrary values of *g*. For  $h = 1$ , at  $T = 0$ , the Fourier amplitudes vary with *g* as  $(g + \Delta - 1)^{-1}$ , according to Eq.  $(25)$ . At higher temperature the jumps will be smeared, giving a more gradual change of  $\langle e^{i\theta} \rangle$  as *B* is varied. This smearing causes the Fourier amplitudes at the higher *g*'s to vanish exponentially.

We see from the above that at low temperatures, the AB Fourier amplitude will be larger than the CD amplitude if the jump parameter  $\Delta$  satisfies  $0 < \Delta < 1/2$ , while the reverse is true if  $1/2 < \Delta < 1$ . We find similarly at high temperatures that the AB component will be larger than the CD component if, and only if,  $\Delta < 1/2$ . For the IQHE  $\Delta$  is purely a consequence of bulk-edge coupling, and it is equal to  $K_{IL}/K_I$ . It vanishes in the extreme AB  $\vert$ imit ( $K_{IL} \rightarrow 0$ ) and approaches 1 in the extreme CD limit ( $K_{IL} \rightarrow K_I$ ). For the FQHE, the value of  $\Delta$  depends on the statistical phase angle  $\theta_a$  and the ratio  $K_{IL}/K_I$ , according to Eq. [\(20\)](#page-7-0), going from  $|\theta_a|/2\pi$ , in the absence of bulk-edge coupling, to 1, when this coupling is strong. This suggests the possibility that one could obtain a direct measure of  $\theta_a$  by observing the discrete jump in the interference phase  $\theta_a$  as an additional quasihole enters the interferometer at low temperatures. In order to extract the value of  $\theta_a$ , however, one would have to independently find a measure of  $K_{IL}/K_I$ , or be able to vary  $K_{IL}$  (say, by varying the area of the interferometer) and extrapolate to  $K_{IL} = 0.$ 

We have said little about the actual values of the parameters *β* and *γ* which determine the gate-voltage periods of the AB and CD stripes, nor have we estimated the energy parameters  $K_I, K_L, K_{IL}$ , which determine the ratio between the AB and CD amplitudes and the temperature dependence of these amplitudes.

One might try to estimate  $\beta$  and  $\gamma$  by using a simplified model, where the electron density in the sample depends on *VG* but is independent of  $B$ . According to Eq.  $(11)$ , this means that if one considers a sample with fixed gate voltage, at various values of *B*, corresponding to different bulk filling factors, the parameter  $\beta$  will be proportional to *B*, while  $\gamma$  will be independent of *B*. Using Eq.  $(34)$  we find that the  $V_G$  period for a CD stripe should be equal to  $e_{\text{out}}^*/(\gamma - \beta v_{\text{out}})$ . The filling factor *ν*out will depend on the magnetic field, but also may be varied by changing the voltage on the gates defining the quantum point-contact constrictions of the interferometer. It appears that the dependence of the gate period on *B* and *VG* predicted by these considerations is only partly in agreement with experiment, and that significant effects are omitted from this simple model. $13,16$ 

Although the energy  $K_L$  may be largely determined by the geometric capacitance of the island, the parameters *KIL* and  $K_I$  should be sensitive to the detailed structure of the edge and are difficult to estimate without a detailed microscopic model and a numerical calculation. The values of these parameters should depend also on the value of the magnetic field and on the setting of the constrictions, which determines which edge mode is the interfering one. For a dot of sufficiently large area, covered by a top gate, the parameter  $K_{IL}$  should decrease inversely as the area, so for an integer quantized Hall state, one would be necessarily in the AB regime. However, the converse is not true; for a small area dot one could be in the CD or AB regime depending on details. Further investigation of these points will be left for future work.

It should be noted that the quantities  $v_{\text{in}}$  and  $v_{\text{out}}$ , which entered our discussion in a most fundamental way, and which, together with the area  $A$ , determined (at least approximately) the field period of the CD components, are properties of the constrictions, and are not sensitive to the filling factor in the bulk. We have only assumed that the bulk electron density is not smaller than the density in the constrictions, and that the *RC* time for relaxation of charge inhomogeneities inside the interferometer is shorter than the experimental time scale for variations of the magnetic field or gate voltage.<sup>[52](#page-16-0)</sup> The values of *ν*in and *ν*out may be determined experimentally by varying the voltage on the pincer electrodes that define one of the two constrictions in the interferometer, while the second constriction is kept open. As the pincer voltage is varied, one will typically pass through a sequence of intervals where the diagonal conductance  $R_D^{-1}$  of the device has a plateau at

<span id="page-15-0"></span>quantized values  $v_i e^2/h$ . If the pincer voltage is now chosen to lie at an intermediate value between two successive plateau values, with  $v_i < v_{i+1}$ , we expect there to be a partially reflected edge state in the constriction, separating  $v_{\text{out}} = v_i$ from  $v_{\text{in}} = v_{i+1}$ . The filling factor in the constriction can also be varied by changing the magnetic field, with the pincer voltage held fixed.

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# **ACKNOWLEDGMENTS**

We acknowledge support from NSF Grant No. DMR-0906475, from the Microsoft Corporation, the BSF, the Minerva foundation, and the BMBF. We have benefited from helpful discussions with C. M. Marcus, D. McClure, Y. Zhang, A. Kou, M. Heiblum, N. Ofek, A. Bid, Y. Dinaii, V. Goldman, and R. Willett.

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